

Technical Data Data Sheet N0810, Rev. - **Green Products**

MBRD3045CT SCHOTTKY RECTIFIER

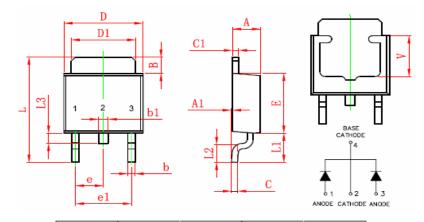
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150 °C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In Inches / mm



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.430	0.580	0.017	0.023	
c1	0.430	0.580	0.017	0.023	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
E	5.400	5.700	0.213	0.224	
е	2.300 TYP.		0.091 TYP.		
e1	4.500	4.700	0.177	0.185	
L	9.500	9.900	0.374	0.390	
L1	2.550	2.900	0.100	0.114	
L2	1.400	1.780	0.055	0.070	
L3	0.600	0.900	0.024	0.035	
V	3.800	REF.	0.150	REF.	

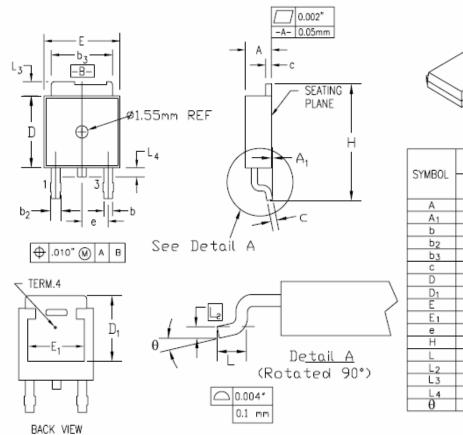
OPTION 1

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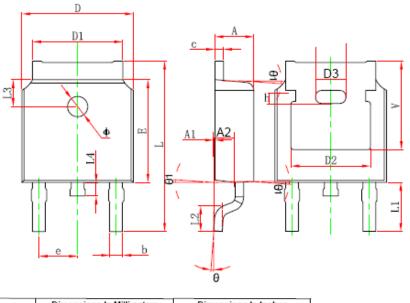
	ASE THODE	
	0.2	A 3
ANODE CA	THODE	ANODE

SYMBOL	INC	HES	MILLIMETERS	
SIMBUL	MIN.	MAX.	MIN.	MAX.
A	0.086	0.094	2.19	2.38
A1	-	0.005	-	0.13
b	0.025	0.035	0.64	0.89
b2	0.033	0.045	0.84	1.14
b3	0.205	0.215	5.21	5.46
С	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
D1	0.205	-	5.21	-
E	0.250	0.265	6.35	6.73
E1	0.190	-	4.83	-
e	0.090	BSC	2.29 BSC	
Н	0.380	0.410	9.65	10.41
L	0.055	0.070	1.40	1.78
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4	0.025	0.040	0.64	1.01
θ	0°	8°	0°	8°

OPTION 2



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Symbol	Dimensions In Millimeters		Dimensions In Inches				
Symbol	Min.	Max.	Min.	Max.	1		
Α	2.200	2.380	0.087	0.094	1		
A1	0.000	0.100	0.000	0.004	1	Base	
b	0.710	0.810	0.028	0.032		common	
С	0.460	0.560	0.018	0.022	1	Cathode	
D	6.500	6.700	0.256	0.264	1	02	
D1	5.130	5.460	0.202	0.215		Υ ²	
D2	4.830	REF.	0.190	REF.	1		
E	6.000	6.200	0.236	0.244	1		
е	2.186	2.386	0.086	0.094			
L	9.800	10.400	0.386	0.409	1 +		\downarrow
L1	2.900	REF.	0.114	REF.	1 ♠		
L2	1.400	1.700	0.055	0.067]		
L3	1.600	REF.	0.063	REF.	61		63
L4	0.600	1.000	0.024	0.039	Anode		Anode
Φ	1.100	1.300	0.043	0.051			
θ	0°	8°	0°	8°	1		
A2	0.910	1.110	0.036	0.044	1		
V	5.350	REF.	0.211	REF.]		
D3	1.778	REF.	0.070	REF.			
h	0.762	REF.	0.030	REF.]		
θ1	7		7		1		

OPTION 3(CJ)

DPAK

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Marking Diagram:



Where XXXXX is YYWWL

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRD3045CT	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	45	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =123°C, rectangular wave form	30	A
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	240	A

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop *	V _{F1}	@ 30 A, Pulse, T _J = 25 °C	0.84	V
max remark renage prop	V_{F2}	@ 30 A, Pulse, T _J = 125 °C	0.72	V
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = rated V_R$ T _C = 25 °C	0.2	mA
	I _{R2}	$@V_R = rated V_R$ T _c = 125 °C	40	mA
Max. Junction Capacitance (per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	500	pF
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

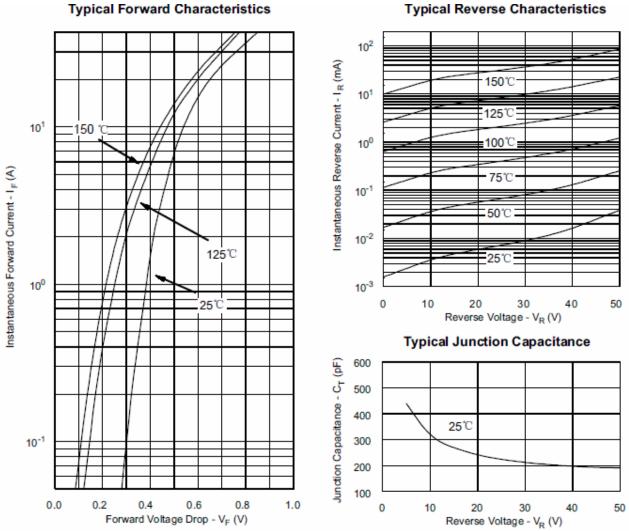
* Pulse Width < 300 μ s, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature Range	TJ	-	-55 to +150	°C
Storage Temperature Range	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	4.5	°C/W
Approximate Weight	wt	-	0.39	g
Case Style		DPAK		



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Typical Reverse Characteristics

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